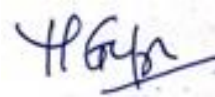


Date: 03.03.24

In continuous with the notice dated 22-02-24 regarding the position of JRF for the project entitled "**Design, Optimization and Fabrication of Radiation Hardened Sub 0.15 micron gate length InAlN/GaN HEMT for Ku band application.**" under DST-SERB, the last date for the same has been extended till **15.03.24**.



**Sr. Prof. Mridula Gupta**  
**Principal Investigator**  
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**University of Delhi South Campus, New Delhi 110021**

**Sr. Prof. Mridula Gupta**  
**Principal Investigator**  
**DST-SERB Sponsored Project on**  
**"Design, Optimization and Fabrication of**  
**Radiation Hardened Sub 0.15 micron gate**  
**length InAlN/GaN HEMT for Ku band application."**